



BST39

350V NPN HIGH-VOLTAGE TRANSISTOR IN SOT89

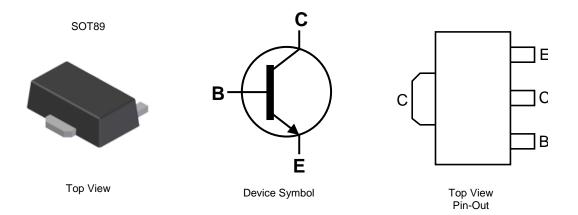
Features

- BVcEo > 350V
- Ic = 0.5A High Continuous Current
- Icm = 1A Peak Pulse Current
- High HFE Hold Up
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: SOT89
- Package Material: Molded Plastic, "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.072 grams (Approximate)



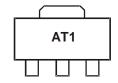
Ordering Information (Note 4)

Part Number	Package	ackage Marking Reel Size (inches)		Tape Width (mm)	Packing	
Fait Number	Fackage	Ivial Killy	Reel Size (Iliches)	rape widin (ililii)	Qty.	Carrier
BST39TA	SOT89	AT1	7	12	1,000	Reel
BST39-13R	SOT89	AT1	13	12	4,000	Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



AT1 = Product Type Marking Code



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	400	V
Collector-Emitter Voltage	VCEO	350	V
Emitter-Base Voltage	VEBO	7	V
Continuous Collector Current	Ic	500	mA
Peak Pulse Current	Ісм	1	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		1		
Power Dissipation	(Note 6)	PD	1.5	W	
	(Note 7)		2.0		
	(Note 5)		125	°C/W	
Thermal Resistance, Junction to Ambient Air	(Note 6)	Reja	83		
	(Note 7)		60		
Thermal Resistance, Junction to Lead	(Note 8)	Rejl	22		
Thermal Resistance, Junction to Case	(Note 9)	Rejc	16		
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C		

ESD Ratings (Note 10)

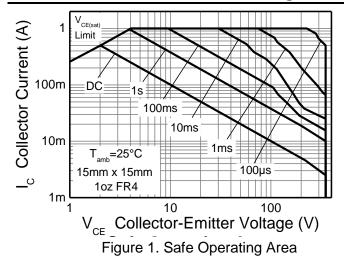
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
- 7. Same as Note 5, except the device is mounted on 50mm x 50mm 1oz copper.
- 8. Thermal resistance from junction to solder-point (on the exposed collector pad).
- 9. Thermal resistance from junction to the top of the case.
- 10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information



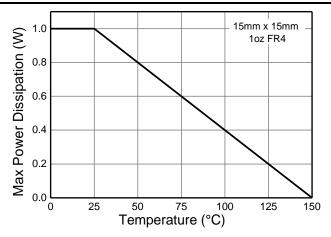


Figure 2. Derating Curve

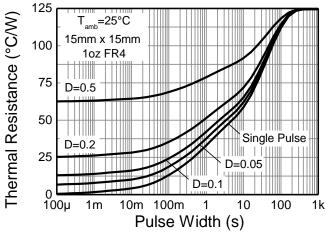
Single Pulse

T_{amb}=25°C

15mm x 15mm

1oz FR4

100



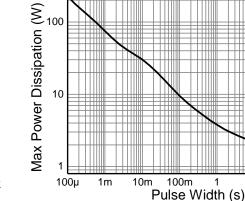
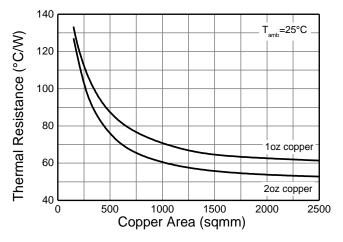


Figure 3. Transient Thermal Impedance Figure





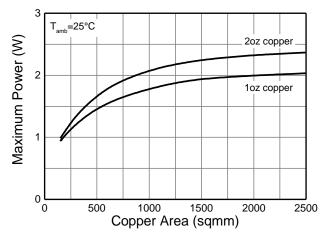


Figure 5. R_{θJA} vs. Copper Area

Figure 6. Power Dissipation vs. Copper Area



Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВУсво	400	_	_	V	Ic = 100μA
Collector-Emitter Breakdown Voltage (Note 11)	BVceo	350	_	_	V	Ic = 1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	_	_	V	I _E = 100μA
Collector Cutoff Current	Ісво	_	_	20	nA	Vcb = 300V
DC Current transfer Static Ratio (Note 11)	hfE	40	_	_	_	Ic = 20mA, VcE = 10V
Collector-Emitter Saturation Voltage (Note 11)	V _{CE(sat)}	_	_	0.5	V	$I_C = 50mA$, $I_B = 4mA$
Base-Emitter Saturation Voltage (Note 11)	V _{BE(sat)}	_	_	1.3	V	$I_C = 50mA$, $I_B = 4mA$
Transitional Frequency (Note 11)	fτ	70	_		MHz	$I_C = 10$ mA, $V_{CE} = 10$ V, $f = 5$ MHz
Output Capacitance	Cobo	_	_	2	pF	V _{CB} = 10V, f = 1MHz, I _E = 0
Input Capacitance	Cibo	_	_	20	pF	V _{EB} = 10V, f = 1MHz, I _C = 0

Note:

11. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤2%.



Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

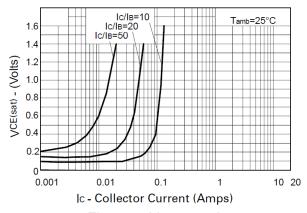


Figure 7. $V_{CE(sat)}$ vs. I_C

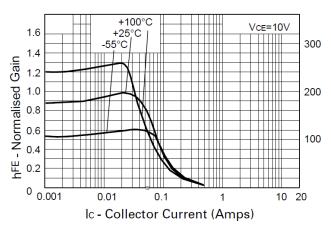
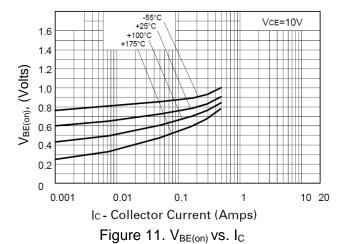


Figure 9. hFE vs. IC



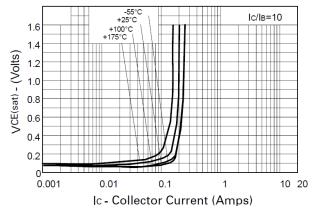


Figure 8. V_{CE(sat)} vs. I_C

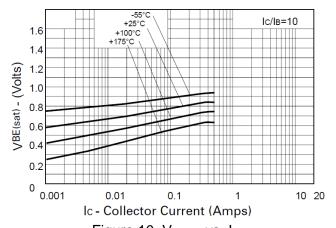


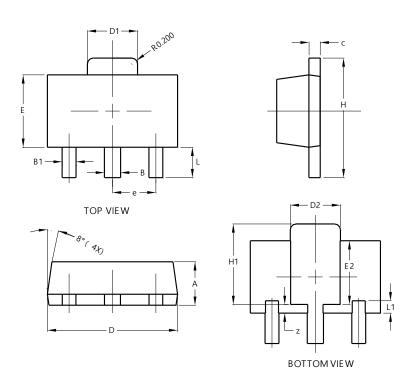
Figure 10. $V_{\text{BE(sat)}}$ vs. I_{C}



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89

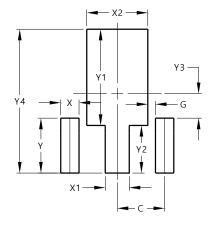


SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
C	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	-	-	1.50		
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
Z	0.20	0.40	0.30		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89



Dimensions	Value (in mm)		
С	1.500		
G	0.244		
Х	0.580		
X1	0.760		
X2	1.933		
Υ	1.730		
Y1	3.030		
Y2	1.500		
Y3	0.770		
Y4	4.530		



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